

50 MHz to 850 MHz, CASCADABLE **ACTIVE BIAS InGaP HBT MMIC AMPLIFIER**

Package: SOT-89

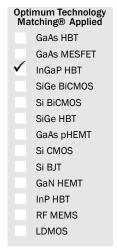


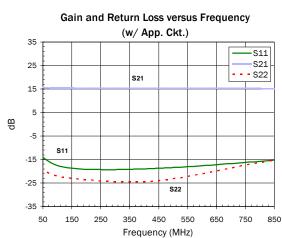
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Product Description

RFMD's SBB1089Z is a high performance InGaP HBT MMIC amplifier utilizing a Darlington configuration with an active bias network. The active bias network provides stable current over temperature and process Beta variations. Designed to run directly from a 5V supply, the SBB1089Z does not require a dropping resistor as compared to typical Darlington amplifiers. The SBB1089Z product is designed for high linearity 5V gain block applications that require small size and minimal external components. It is internally matched to 50Ω .





Features

- OIP₃=43.1dBm at 240MHz
- P_{1dB}=19.6dBm at 500MHz
- Single Fixed 5V Supply
- Robust 1000V ESD, Class 1C
- Patented Thermal Design and Bias Circuit
- Low Thermal Resistance

Applications

- Receiver IF Amplifier
- Cellular, PCS, GSM, UMTS
- Wireless Data, Satellite **Terminals**

	Specification		Unit	Condition	
Min.	Тур.	Max.	UIIIL	Condition	
	15.5		dB	70MHz	
14.0	15.5	17.0	dB	240 MHz	
14.0	15.5	17.0	dB	400 MHz	
	19.0		dBm	70MHz	
	19.0		dBm	240 MHz	
18.0	19.0		dBm	400 MHz	
	42.0		dBm	70MHz	
	43.0		dBm	240 MHz	
38.5	40.5		dBm	400 MHz	
	50 to 850		MHz	Minimum 10dB	
14.0	18.0		dB	70 MHz to 5000 MHz	
12.0	16.0		dB	70 MHz to 5000 MHz	
	3.5	4.2	dB	500 MHz	
	18.0		dB	70MHz to 5000MHz	
	48.8		°C/W	junction - lead	
	5.0	5.3	V		
82.0	90.0	98.0	mA		
	14.0 14.0 18.0 38.5 14.0 12.0	Min. Typ. 15.5 14.0 15.5 14.0 15.5 14.0 15.5 19.0 19.0 42.0 43.0 38.5 40.5 50 to 850 14.0 18.0 12.0 16.0 3.5 18.0 48.8 5.0	Min. Typ. Max. 15.5 17.0 14.0 15.5 17.0 19.0 19.0 19.0 42.0 43.0 38.5 40.5 50 to 850 14.0 18.0 12.0 16.0 3.5 4.2 18.0 48.8 5.0 5.3	Min. Typ. Max. 15.5 dB 14.0 15.5 17.0 dB 14.0 15.5 17.0 dB 19.0 dBm dBm dBm 18.0 19.0 dBm 42.0 dBm dBm 38.5 40.5 dBm 50 to 850 MHz 14.0 18.0 dB 12.0 16.0 dB 18.0 dB dB 48.8 °C/W 5.0 5.3 V	

Test Conditions: $V_D = 5V$, $I_D = 90$ mA Typ., OIP₃ Tone Spacing = 1MHz, P_{OIIT} per tone = 0dBm, $T_1 = 25^{\circ}$ C, $Z_S = Z_1 = 50\Omega$, Tested with Bias Tees

DS100809



Absolute Maximum Ratings

Parameter	Rating	Unit
Device Current (I _D)	110	mA
Device Voltage (V _D)	5.5	V
RF Input Power	24	dBm
Junction Temp (T _J)	+150	°C
Operating Temp Range (T _L)	-40 to +85	°C
Storage Temp	+150	°C
Power Dissipation	0.61	W
ESD Rating - Human Body Model (HBM)	Class 1C	
Moisture Sensitivity Level	MSL2	

Operation of this device beyond any one of these limits may cause permanent damage. For reliable continuous operation, the device voltage and current must not exceed the maximum operating values specified in the table on page one. Bias Conditions should also satisfy the following expression: $I_DV_D \! < \! (T_J \! - \! T_L) / R_{TH}, j \! - \! l \text{ and } T_L \! = \! T_{LEAD}$



Caution! ESD sensitive device.

Exceeding any one or a combination of the Absolute Maximum Rating conditions may cause permanent damage to the device. Extended application of Absolute Maximum Rating conditions to the device may reduce device reliability. Specified typical performance or functional operation of the device under Absolute Maximum Rating conditions is not implied.

RoHS status based on EU Directive 2002/95/EC (at time of this document revision).

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Typical RF Performance at Key Operating Frequencies (With 240MHz Application Circuit)

Parameter	Unit	50MHz	70MHz	100	240	400	500	850
				MHz	MHz	MHz	MHz	MHz
Small Signal Gain, S ₂₁	dB	16.0	15.5	15.5	15.5	15.5	15.5	15.0
Output Third Order Intercept Point, OIP ₃	dBm	41.5	42.0	43.0	43.0	41.0	40.0	35.0
Output Power at 1dB Compression, P _{1dB}	dBm	19.0	19.0	19.0	19.0	19.0	19.0	18.0
Input Return Loss, S ₁₁	dB	13.0	16.0	17.0	19.0	19.0	18.0	15.0
Output Return Loss, S ₂₂	dB	18.0	20.0	21.0	23.0	24.0	23.0	17.0
Reverse Isolation, S ₁₂	dB	18.0	18.0	18.0	18.0	18.0	18.0	18.0
Noise Figure, NF	dB	3.5	3.3	3.2	3.1	3.2	3.2	3.4

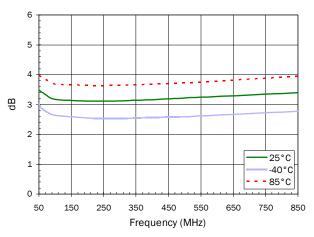
 $\begin{tabular}{ll} Test Conditions: $V_{CC}=5V$ & $I_D=90\,\text{mA Typ.}$ & OIP_3 Tone Spacing = 1MHz, P_{OUT} per tone = 0dBm $T_L=25\,^{\circ}C$ & $Z_S=Z_L=50\Omega$ & $I_D=20\,^{\circ}C$ & $I_D=20\,^{\circ}$



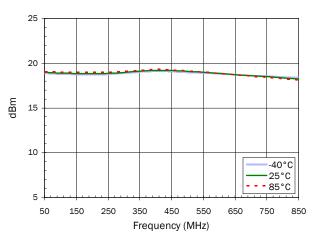


Data on Charts taken with 240 MHz App. Ckt.

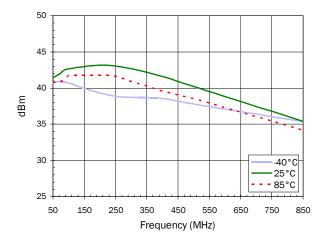
Noise Figure versus Frequency



P1dB versus Frequency



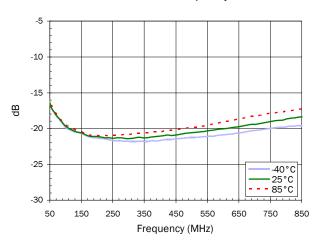
OIP3 versus Frequency



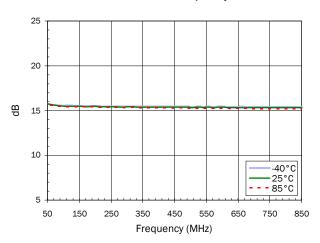


S-Parameters over Temperature (Bias Tee)

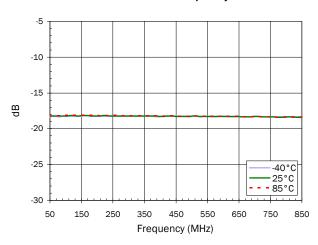
S11 versus Frequency



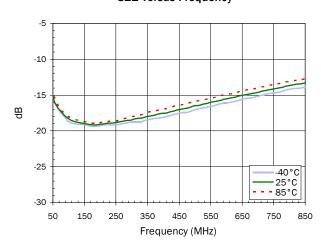
S21 versus Frequency



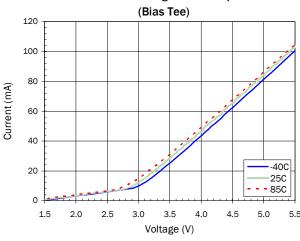
S12 versus Frequency



S22 versus Frequency



Current versus Voltage Over Temperature

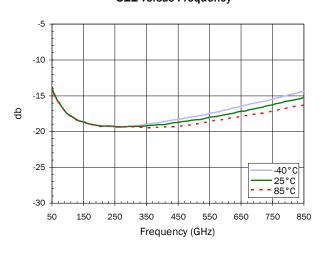




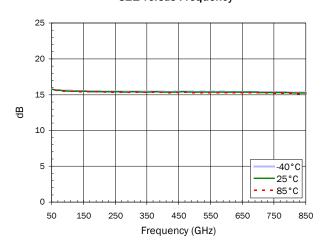


240 MHz Application Circuit S-Parameters over Temperature

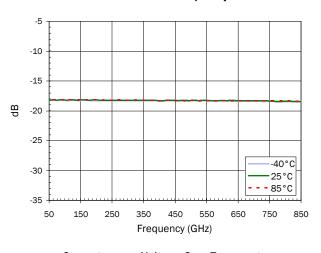
S11 versus Frequency



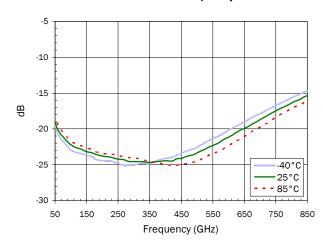
S21 versus Frequency



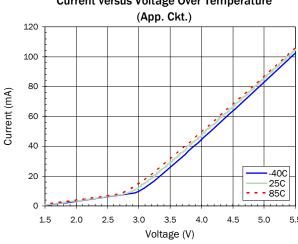
S12 versus Frequency



S22 versus Frequency



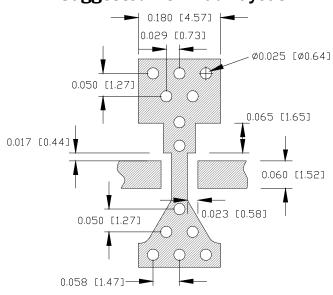
Current versus Voltage Over Temperature





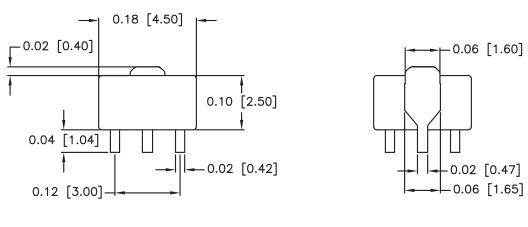
Pin	Function	Description
1	RF IN	RF input pin. This pin requires the use of an external DC blocking capacitor chosen for the frequency of operation.
2, 4	GND	Connection to ground. Use via holes for best performance to reduce lead inductance as close to ground leads as possible.
3	RF OUT/BIAS	RF output and bias pin. DC voltage is present on tis pin, therefore a DC blocking capacitor is necessary for proper operation.

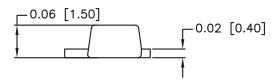
Suggested PCB Pad Layout



Package Drawing

Dimensions in inches (millimeters)
Refer to drawing posted at www.rfmd.com for tolerances.





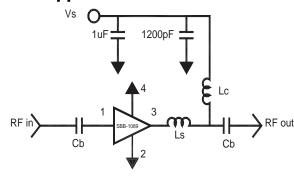


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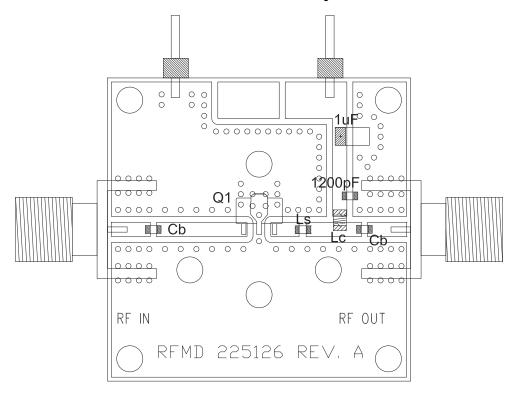
Application Circuit Element Values

Reference	Frequency (MHZ)		
Designator	50 to 850		
СВ	8200pF		
L _C	1500nH 0805LS Coilcraft		
L _S	2.7 nH Toko		

Application Schematic



Evaluation Board Layout





Package Marking



Alternate marking is "SBB1089Z" on line 1 with Trace Code on line 2.

Ordering Information

Ordering Code	Description
SBB1089Z	7" Reel with 1000 pieces
SBB1089ZSQ	Sample Bag with 25 pieces
SBB1089ZSR	7" Reel with 100 pieces
SBB1089ZPCK	50MHz to 850MHz PCBA with 5-piece sample bag